L Number	Hits	Search Text	DB	Time stamp
1	613	438/22.ccls. or 438/26.ccls.	USPAT	2003/12/01 08:40
3	534	438/689.ccis. or 438/690.ccis.	USPAT	2003/12/01 08:41
5	1438	((438/691).CCLS. OR (438/692).CCLS.) not (438/689.ccls. or	USPAT	2003/12/01 08:44
	1400	438/690.ccls.)	DOLVI	2003/12/01 00:44
	530	134/1.3.ccls.	USPAT	2003/11/20 15:17
-	25	134/1.3.ccls. and (wip\$3)	USPAT	2003/11/20 15:17
- 1	15	((TFT or (thin adj film adj transistor\$2))) and (flattening adj	USPAT	2003/11/20 15:16
-	10	treatment)	USPAT	2003/11/20 15:45
}	0		HODAT	2002/44/20 45:45
-	0	(flattening adj treatment) with anode	USPAT	2003/11/20 15:45 2003/11/20 15:45
· ·	41	flattening with anode	USPAT	
-	8	((TFT or (thin adj film adj transistor\$2))) and (flattening with	USPAT	2003/11/20 15:45
}		anode)		
-	773	((TFT or (thin adj film adj transistor\$2))) and (polyvinyl adj	USPAT	2003/11/20 16:13
 		alcohol)		
-	208	TFT and resin and ((CMP or planariz\$6) with (pixel or anode or	USPAT	2003/11/20 16:14
	1	electrode))		
i -	152	(TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAT	2003/11/20 16:16
]		or electrode))) not (semiconductor and energy and		
1		(aboratory).as.		
-	0	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAT	2003/11/20 16:16
		or electrode))) not (semiconductor and energy and		
		laboratory).as.) and (anode with CMP)	,	
1 -	20	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAT	2003/11/20 16:19
		or electrode))) not (semiconductor and energy and		
1 !		laboratory).as.) and anode	[
1_	112	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAT	2003/11/20 16:19
()	· '-	or electrode))) not (semiconductor and energy and	00.7	2000, 1,1120, 101.10
j !		laboratory).as.) and (pixel adj electrode)	1	
j l	0	(((TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAT	2003/11/20 16:19
		or electrode))) not (semiconductor and energy and	00171	2000/11/20 10:10
1		laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with	l	
1 1			1	
		anode)	USPAT	2003/11/20 16:22
-	44	(((TFT and resin and ((CMP or planariz\$6) with (pixel or anode	USPAI	2003/11/20 10.22
		or electrode))) not (semiconductor and energy and	}	
,		laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with		
i i		pixel)	USPAT	2003/11/20 16:24
-	1	((((TFT and resin and ((CMP or planariz\$6) with (pixel or	USPAI	2003/11/20 10.24
	(anode or electrode))) not (semiconductor and energy and		
1	(laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with		
		pixel)) and (pixel with CMP)		
[-	8	TFT and display\$1 and ((anode or pixel) with (clean\$3 and	USPAT;	2003/11/20 16:29
		flatten\$3))	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
-	73		USPAT	2003/12/01 08:39
		mechanical adj polish\$3) or clean\$3 or wip\$3 or flat\$6)) and	1	
[1	(TFT or (thin adj film adj transistor\$2))		